# NSN 5961-01-183-6506

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## **Inclosure Material:**

Metal

**Overall Length:** 

0.210 inches

# Terminal Length:

0.500 inches

## **Overall Diameter:**

0.230 inches

#### Internal Configuration:

Junction contact

### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-72

#### **Mounting Method:**

Terminal

#### Terminal Circle Diameter:

0.100 inches

#### **Features Provided:**

Hermetically sealed case

### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

20.0 collector to base voltage/static/emitter open and 14.0 collector to emitter voltage/static/base open and 3.0 emitter to base voltage, static, collector open

# **Current Rating Per Characteristic:**

125.00 milliamperes source cutoff current

### **Power Rating Per Characteristic:**

450.0 milliwatts small-signal input power, common-collector preset

#### **Transfer Ratio:**

200.0 static forward current transfer ratio, common-emitter

# Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

# **Special Features:**

Junction pattern arrangement: npn

# **Terminal Type And Quantity:**

3 uninsulated wire lead

# Shelf Life:

N/a

Unit Of Measure:

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## Demilitarization:

No

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